

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	121	349/140	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 14:17
L2	35	1 and light adj4 (shield\$3 intercept\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 14:01
L3	7	1 and (active semiconductor) adj (layer film) same light adj4 (shield\$3 intercept\$3 block\$3 absorption)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 14:17
L4	1760	349/43	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 14:17
L5	193	4 and (active semiconductor) adj (layer film) same light adj4 (shield\$3 intercept\$3 block\$3 absorption)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 16:02
L6	65	5 and overlap\$4 with (data video signal) adj4 line	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 14:19
L7	1	"6466289".pn.	USPAT	OR	OFF	2004/12/29 15:25
L8	1	"5907379".pn.	USPAT	OR	OFF	2004/12/29 15:29
L9	1	"6133977".pn.	USPAT	OR	OFF	2004/12/29 15:42
L10	2	"20010040663".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 15:31
L11	1	"6043511".pn.	USPAT	OR	OFF	2004/12/29 15:42
L12	2111	semiconductor adj (layer film) same light adj4 (shield\$3 intercept\$3 block\$3 absorption)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 16:08
L13	1432	semiconductor adj (layer film) with light adj4 (shield\$3 intercept\$3 block\$3 absorption)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 16:03
L14	95	13 and (ips in?plane)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 16:04
L15	1191	semiconductor adj4 light adj (shield\$3 intercept\$3 block\$3 absorption)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 16:09
L16	150	light adj (shield\$3 intercept\$3 block\$3 absorption) with semiconductor adj material	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 16:10

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L2	35	1 and light adj4 (shield\$3 intercept\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 14:01
L3	7	1 and (active semiconductor) adj (layer film) same light adj4 (shield\$3 intercept\$3 block\$3 absorption)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 14:17
L4	1760	349/43	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 14:17
L5	193	4 and (active semiconductor) adj (layer film) same light adj4 (shield\$3 intercept\$3 block\$3 absorption)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 14:18
L6	65	5 and overlap\$4 with (data video signal) adj4 line	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/12/29 14:19